

# APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS
Capacitor Arrays Series (10V to 100V)
4 x 0402, 4 x 0603 Sizes
NP0, X7R & Y5V Dielectrics
Halogen Free & RoHS Compliance

\*Contents in this sheet are subject to change without prior notice.

#### 1. INTRODUCTION

WTC middle and high voltage series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords increased capacitance values in a given case size and voltage rating.

WTC capacitor arrays are developed to offer designers the opportunity to lower placement costs increase assembly line output through lower component count per board.

#### 2. FEATURES

- a. High density mounting due to mounting space saving.
- b. Mounting cost saving.
- c. Increased throughput.

#### 3. APPLICATIONS

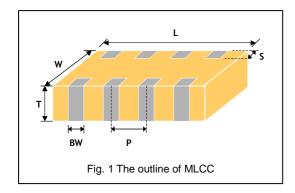
- For use as a bypass for digital and analog signal line noise
- b. Computer motherboards and peripherals.
- c. The other common electronic circuits.

#### **4. HOW TO ORDER**

				1+	12			
<u>Y</u>	<u>4C</u>	<u>3</u>	<u>B</u>	<u>103</u>	<u>K</u>	<u>500</u>	<u>C</u>	I
<u>Series</u>	Cap. Nr.	Termination pitch	<u>Dielectric</u>	Capacitance	Tolerance	Rated voltage	<u>Termination</u>	<u>Packaging</u>
Y=Capacitor array	<b>4C</b> =4xCap	<b>3</b> =0.03" pitch* <b>2</b> =0.02" pitch*	N=NP0 (C0G)	digits followed	<b>J</b> =±5% <b>K</b> =±10%	Two significant digits followed	<b>C</b> =Cu/Ni/Sn	<b>T</b> =7" reeled
			<b>B</b> =X7R <b>F</b> =Y5V	by no. of zeros. And R is in	<b>Z</b> =-20/+80%	by no. of zeros. And R is in		
Y	/4C3: 4x060	3 (0612)	No.	place of decimal point.	LLIANCE	place of decimal point.		
Y	/4C2: 4x040	2 (0508)		eg.: 103=10x10 <sup>3</sup>	Cologo	eg.: <b>100</b> =10 VDC		
			SAITE	=10,000pF	RATION, ALL	<b>160</b> =16 VDC <b>250</b> =25 VDC		
				- JUNI CONT		<b>500</b> =50 VDC <b>101</b> =100 VDC		

<sup>\*</sup>Size/ Inch (mm): 4x0402=0508 (1220), 4x0603=0612 (1632)

#### 5. EXTERNAL DIMENSIONS



Size Inch (mm)	L (mm)	W (mm)	T (mm)/Sym	bol	S (mm)	BW (mm)	P (mm)
4x0402 0508 (1220)	2.00±0.15	1.25±0.15	0.85±0.10	Т	0.20±0.10	0.25±0.10	0.50±0.10
4x0603 0612 (1632)	3.20±0.15	1.60±0.15	0.80±0.10	В	0.30±0.20	0.40±0.15	0.80±0.15

Reflow soldering process only.

# **6. GENERAL ELECTRICAL DATA**

	1441/7	A				
Dielectric	NF NF	90	X7	X7R		
Size	4x0402	4x0603	4x0402	4x0603	4x0603	
Inch (mm)	0508 (1220)	0612 (1632)	0508 (1220)	0612 (1632)	0612 (1632)	
Capacitance*	10pF to 270pF	=10pF to 470pF∈	1000pF to 100nF	150pF to 100nF	10nF to 100nF	
Capacitance tolerance**	J (±5%), K (±10%)		K (±10%),	Z (-20/+80%)		
Rated voltage (WVDC)	25, 50V, 100V		10V, 16V, 25V, 50V	16V, 25V, 50V	16V, 50V	
Q/Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		Ur=50V Ur=25V&1 Ur=10V	6V, ≤3.5%	Ur=50V, ≤5% Ur=16V, ≤7%	
Insulation resistance at Ur	≥10	GOCHIDION	≥10GΩ	or RxC≥500ΩxF which	chever is less	
Operating temperature		55 to	) +125℃	-25 to +85℃		
Capacitance characteristic	±30ppm		±15%		+30/-80%	
Termination			Ni/Sn (lead-free term	nination)		

<sup>\*</sup> Measured at 30~70% related humidity.

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% at the conditions of 25℃ ambient temperature.

X7R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 25℃ ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 20℃ ambient temperature.

<sup>\*\*</sup> Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in a mbient condition for 24±2 hours before measurement.

#### 7. CAPACITANCE RANGE

	SIZE Inch (mm)			C	4 x 040 508 (12				4x0603 0612 (1632)							
D	DIELECTRIC		NP0 X7R			NPO X7R				Y5V						
RAT	ED VOLTAGE	25	50	100	10	16	25	50	25	50	100	16	25	50	16	50
	(VDC)	Т	Т	Т					В	В	В					
	10pF (100)	T	T	T					В	В	В					
	15pF (150) 22pF (220)	T	T	T					В	В	В					
	33pF (330)	T	T	T					В	В	В					
	47pF (470)	T	T	T					В	В	В					
	68pF (680)	T	T	T					В	В	В					
	100pF (101)	T	T	T					В	В	В					
	120pF (121)	T	T	T					В	В	В					
	150pF (151)	T	T	T					В	В	В		В	В		
	180pF (181)	T	T	T					В	В	В		В	В		
	220pF (221)	T	T	T					В	В	В		В	В		
	270pF (271)	Т	Т	Т					В	В	В		В	В		
8	330pF (331)								В	В	В		В	В		
tan	470pF (471)								В	В	В		В	В		
Capacitance	6,80pF (681)												В	В		
Sag	1,000pF (102)				Т	Т	77.7	Бт	13				В	В		
	1,500pF (152)				Т	E	PH	Т	J. S.	Be			В	В		
	2,200pF (222)				T/	/ TO	J	财化	7 x				В	В		
	3,300pF (332)				7, 1	XT 4	$\langle \dot{\tau} \rangle$	ルケル	13	众	7.1		В	В		
	4,700pF (472)				/ <del>\$</del> }//7	, T	T	Т	*	F	156		В	В		
	6,800pF (682)				Ť	//T	Т	Т		$\nabla$			В	В		
	0.010µF (103)				Т	<b>4</b> 7	I	I					В	В		В
	0.015µF (153)				Т	Т	T	7	A			В	В	В		В
	0.022µF (223)				<u>a</u>	TPA	ss <b>T</b> ve	SYSTEM	ALLIA	NCE		В	В	В		В
	0.033µF (333)				1	<b>_T</b>	Т			.0		В				В
	0.047µF (473)				35	T.	Т					В				В
	0.068µF (683)				\1	T	1			6	85/	В				В
	0.10µF (104)				T	T	B.T.		CO	6	31/	В			В	В

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.

## **8. PACKAGING DIMENSION AND QUANTITY**

SIZE	Thickness/Syr	mbol	Paper tape			
Inch (mm)	(mm)		7" reel	13" reel		
4x0402 0508 (1220)	0.85±0.10	Т	4k	-		
4x0603 0612 (1632)	0.80±0.10	В	4k	-		

Unit: pieces



# 9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

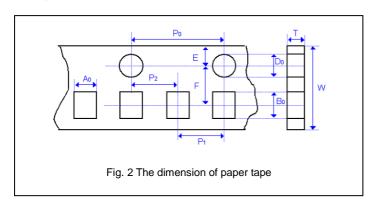
No.	ltem	Test Condition	Requirements			
1.	Visual and		* No remarkable defect.			
	Mechanical		* Dimensions to conform to individual specification sheet.			
2.	Capacitance	Class I: (NP0)	* Shall not exceed the limits given in the detailed spec.			
3.	Q/ D.F.	1.0±0.2Vrms, 1MHz±10%	NP0: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C			
	(Dissipation	Class II: (X7R, Y5V)	X7R: Ur=50V, ≤2.5%; Ur=25V&16V, ≤3.5%; Ur=10V, ≤5.0%			
	Factor)	1.0±0.2Vrms, 1kHz±10%	Y5V: Ur=50V, ≤5%; Ur=16V, ≤7%			
		*Before initial measurement (Class II only): To apply de-aging				
		at 150°C for 1hr then set for 24±2 hrs at room temp .				
4.	Dielectric	* To apply 250% rated voltage.	* No evidence of damage or flash over during test.			
	Strength	* Duration: 1 to 5 sec.				
		* Charge and discharge current less than 50mA.				
5.	Insulation	To apply rated voltage for max. 120 sec.	≥10GΩ or RxC≥500Ω-F whichever is smaller.			
	Resistance	*Before initial measurement (Class II only): To apply de-aging				
		at 150℃ for 1hr then set for 24±2 hrs at room temp.				
6.	Temperature	With no electrical load.				
	Coefficient	T.C. Operating Temp	T.C. Capacitance Change			
		NP0 -55~125℃ at 25℃	NP0 Within ±30ppm/℃			
		X7R   -55~125°C at 25°C Y5V   -25~85°C at 20°C	X7R Within ±15% Y5V Within +30%/-80%			
		*Before initial measurement (Class II only): To apply de-aging	130 /0/-00 /0			
		at 150°C for 1hr then set for 24±2 hrs at room temp.				
7	Adhesive	* Pressurizing force :	* No remarkable damage or removal of the terminations.			
	Strength of	5N (≤0603) and 10N (>0603)	No remarkable damage of removal of the terminations.			
	Termination	* Test time: 10±1 sec.	TIII			
8.	Vibration	* Vibration frequency: 10~55 Hz/min.	* No remarkable damage.			
	Resistance	* Total amplitude: 1.5mm PASSIVE SYSTEM ALL	*Cap change and Q/D.F.: To meet initial spec.			
		* Test time: 6 hrs. (Two hrs each in three mutually				
		perpendicular directions.)				
		*Before initial measurement (Class II only): To apply de-aging				
		at 150℃ for 1hr then set for 24±2 hrs at room temp.	16 CE			
		*Cap./DF(Q) Measurement to be made after de-aging at 150℃				
		for 1hr then set for 24±2 hrs at room temp.	701. 5			
9.	Solderability	* Solder temperature: 235±5℃	95% min. coverage of all metalized area.			
		* Dipping time: 2±0.5 sec.				
10.	Bending Test	* The middle part of substrate shall be pressurized by means	* No remarkable damage.			
		of the pressurizing rod at a rate of about 1 mm per second until				
		the deflection becomes 1 mm and then the pressure shall be	NP0: within ±5.0% or ±0.5pF whichever is larger.			
		maintained for 5±1 sec.	X7R: within ±12.5%			
		*Before initial measurement (Class II only): To apply de-aging	Y5V: within ±30%			
		at 150°C for 1hr then set for 24±2 hrs at room temp.	(This capacitance change means the change of capacitance under			
		*Measurement to be made after keeping at room temp. for 24±2 hrs.	specified flexure of substrate from the capacitance measured before			
11.	Resistance to		the test.)  * No remarkable damage.			
		* Solder temperature: 260±5°C  * Dipping time: 10±1 sec	* Cap change:			
	- Jidoning ricat	* Preheating: 120 to 150°C for 1 minute before imme rse the	NP0: within ±2.5% or ±0.25pF whichever is larger.			
		capacitor in a eutectic solder.	X7R: within ±7.5%			
		*Before initial measurement (Class II only): To apply de-aging	Y5V: within ±20%			
		at 150°C for 1hr then set for 24±2 hrs at room temp.	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.			
		*Cap. / DF(Q) / I.R. Measurement to be made after de-aging at				
		150°C for 1hr then set for 24±2 hrs at room temp.	<u> </u>			
	1	:	:			

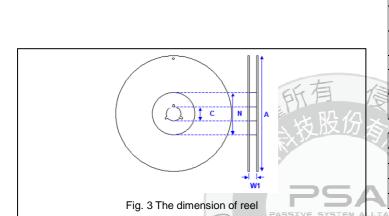
No.	Item		Test Condition		Requirements		
12.	Temperature Cycle	* Conduct time.	the five cycles according to the termore Temp. (°C)	mperatures and Time (min.)	* No remarkable damage.  * Cap change :  NP0: within ±2.5% or ±0.25pF whichever is larger.		
		1 2 3 4	Min. operating temp. +0/-3 Room temp. Max. operating temp. +3/-0 Room temp. itial measurement (Class II only): T	30±3 2~3 30±3 2~3	X7R: within ±7.5% Y5V: within ±20%  * Q/D.F., I.R. and dielectric strength: To meet initial requirements.		
		* Cap. / D	or 1hr then set for 24±2 hrs at roon F(Q) / I.R. Measurement to be made or 1hr then set for 24±2 hrs at roon	de after de-aging			
13.	Humidity (Damp Heat) Steady State	* Humidity  * Test time  *Before in  at 150℃ fo  * Cap. / D	p.: 40±2°C r: 90~95% RH e: 500+24/-0hrs. itial measurement (Class II only): T or 1hr then set for 24±2 hrs at roon F(Q) / I.R. Measurement to be mad or 1hr then set for 24±2 hrs at roon	n temp. de after de-aging	Y5V: within ±30%		
14.	Humidity (Damp Heat) Load	* Humidity * Test time * To apply *Before in at 150°C fo * Cap. / D	p.: 40±2°C  r: 90~95%RH  e: 500+24/-0 hrs.  voltage: rated voltage.  itial measurement (Class II only): 1  or 1hr then set for 24±2 hrs at roon  F(Q) / I.R. Measurement to be made or 1hr then set for 24±2 hrs at	n temp.	* No remarkable damage.  * Cap change: NP0: within ±7.5% or ±0.75pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  * Q/D.F. value:  NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C  X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%  Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%  * I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.		
15.	High Temperature Load (Endurance)	* Test time *Before in at 150℃ fo * Cap. / D	: 125±3°C	To apply de-aging in temp.	* No remarkable damage.  * Cap change: NP0: within ±3.0% or ±0.3pF whichever is larger.  X7R: within ±12.5%  Y5V: within ±30%  * Q/D.F. value:  NP0: Cap≥30pF, Q≥350  10pF≤Cap<30pF, Q≥275+2.5C  Cap<10pF, Q≥200+10C  X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%  Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%  * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		

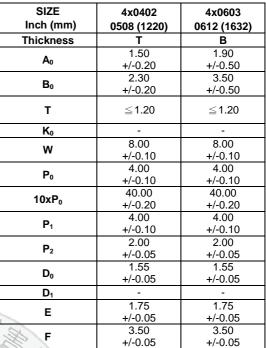
#### <u>APPENDIXES</u>

#### **■ Tape & reel dimensions**

**Multilayer Ceramic Capacitors** 

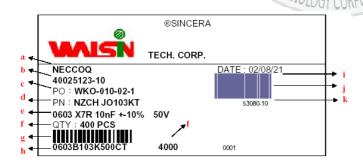






Reel size	7"
CO	13.0+0.5/-0.2
$\mathbf{W}_{1}$	8.4+1.5/-0
A	178.0±1.0
N	60.0+1.0/-0

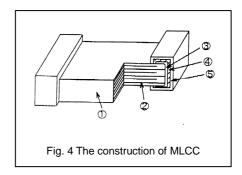
#### **■** Description of customer label



- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label

#### Constructions

No.	Nan	ne	NP0, X7R, Y5V
①	Ceramic r	material	BaTiO₃ based
2	Inner ele	ctrode	Ni
3		Inner layer	Cu
4	Termination	Middle layer	Ni
(5)		Outer layer	Sn (Matt)



#### **■** Storage and handling conditions

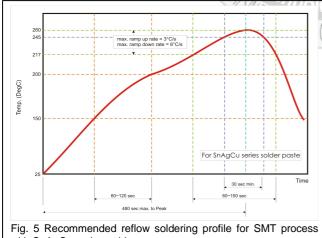
- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

#### Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

### ■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N<sub>2</sub> within oven are recommended.



with SnAgCu series solder paste.

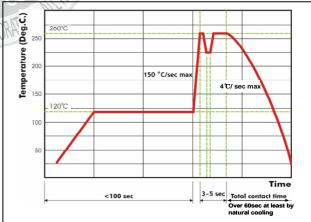


Fig. 6 Recommended wave soldering profile for SMT process with SnAgCu series solder.

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Y4C3F104Z500CT Y4C3B104K160CT